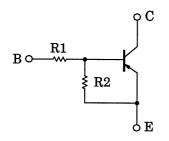
TOSHIBA Transistor Silicon PNP Epitaxial Type (PCT Process)

# RN2907,RN2908,RN2909

Switching, Inverter Circuit, Interface Circuit And Driver Circuit Applications

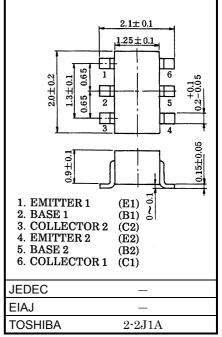
- Including two devices in US6 (ultra super mini type with 6 leads)
- With built-in bias resistors
- Simplify circuit design
- Reduce a quantity of parts and manufacturing process
- Complementary to RN1907~1909

#### **Equivalent Circuit and Bias Resistor Values**



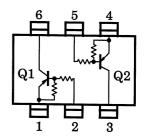
Type No.	R1 (kΩ)	R2 (kΩ)
RN2907	10	47
RN2908	22	47
RN2909	47	22

Unit in mm



Weight: 6.8 mg

### **Equivalent Circuit (Top View)**



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## Maximum Ratings (Ta = 25°C) (Q1, Q2 Common)

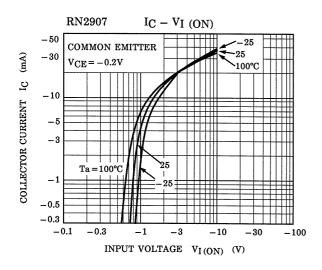
Characterist	Symbol	Rating	Unit		
Collector-base voltage	RN2907~2909	$V_{CBO}$	-50	٧	
Collector-emitter voltage	KN2907~2909	V <sub>CEO</sub>	-50	V	
	RN2907		-6	V	
Emitter-base voltage	RN2908	$V_{EBO}$	-7		
	RN2909		-15		
Collector current		IC	-100	mA	
Collector power dissipation	RN2907~2909	P <sub>C</sub> *	200	mW	
Junction temperature	KN2907~2909	Tj	150	°C	
Storage temperature range		T <sub>stg</sub>	-55~150	°C	

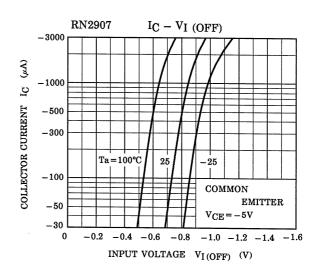
<sup>\*:</sup> Total rating

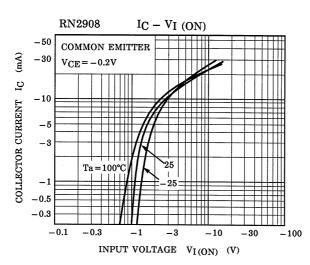
## Electrical Characteristics (Ta = 25°C) (Q1, Q2 Common)

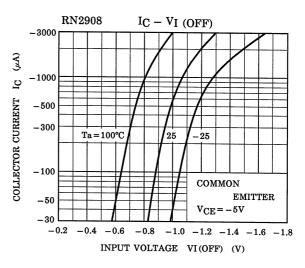
Characteristic		Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	RN2907~2909	I <sub>CBO</sub>	_	$V_{CB} = -50V$ , $I_E = 0$	_	_	-100	nA
	KIN29U/~29U9	I <sub>CEO</sub>	_	V <sub>CE</sub> = -50V, I <sub>B</sub> = 0	_	_	-500	nA
Emitter cut-off current	RN2907	I <sub>EBO</sub>	_	$V_{EB} = -6V, I_C = 0$	-0.081	_	-0.15	mA
	RN2908		_	V <sub>EB</sub> = -7V, I <sub>C</sub> = 0	-0.078	_	-0.145	
	RN2909		_	V <sub>EB</sub> = −15V, I <sub>C</sub> = 0	-0.167	_	-0.311	
DC current gain	RN2907	h <sub>FE</sub>	_	V <sub>CE</sub> = -5V, I <sub>C</sub> = -10mA	80	_	_	_
	RN2908		_		80	_	_	
	RN2909		_		70	_	_	
Collector-emitter saturation voltage	RN2907~2909	V <sub>CE (sat)</sub>	_	I <sub>C</sub> = -5mA, I <sub>B</sub> = -0.25mA	_	-0.1	-0.3	V
Input voltage (ON)	RN2907	V <sub>I (ON)</sub>	_	V <sub>CE</sub> = -0.2V, I <sub>C</sub> = -5mA	-0.7	_	-1.8	V
	RN2908		_		-1.0	_	-2.6	
	RN2909		_		-2.2	_	-5.8	
	RN2907	V <sub>I (OFF)</sub>	_	V <sub>CE</sub> = -5V, I <sub>C</sub> = -0.1mA	-0.5	_	-1.0	V
Input voltage (OFF)	RN2908		_		-0.6	_	-1.16	
	RN2909		_		-1.5	_	-2.6	
Translation frequency	RN2907~2909	f <sub>T</sub>	_	$V_{CE} = -10V, I_{C} = -5mA$	_	200	_	MHz
Collector output capacitance	RN2907~2909	C <sub>ob</sub>	_	$V_{CB} = -10V, I_{E} = 0,$ f = 1MHz	_	3	6	pF
	RN2907		_		7	10	13	
Input resistor	RN2908	R1	_	_	15.4	22	28.6	kΩ
	RN2909		_		32.9	47	61.1	
Resistor ratio	RN2907	R1/R2	_	_	0.191	0.213	0.232	_
	RN2908		_		0.421	0.468	0.515	
	RN2909		_		1.92	2.14	2.35	

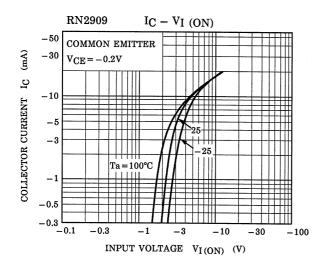
#### (Q1, Q2 Common)

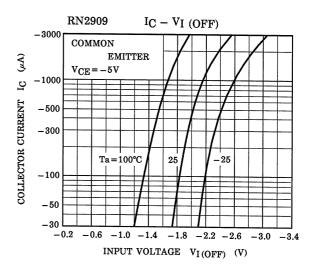




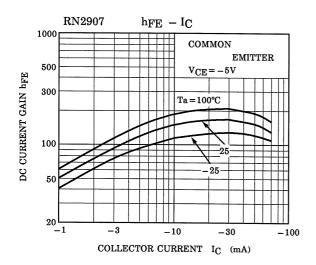


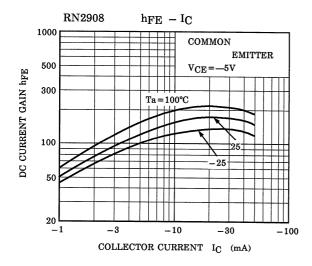


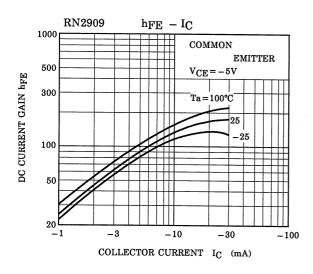




## (Q1, Q2 Common)







Type Name	Marking
RN2907	Type Name YH
RN2908	Type Name YI
RN2909	Type Name  Y J